

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	13	voltage adj sustaining adj region and epitaxial and trench and column with dop\$4 with sidewall	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:55
L2	13	voltage adj sustaining adj region and epitaxial and trench and (column with dop\$4 with sidewall)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:42
L3	0	voltage adj sustaining adj region and epitaxial and trench and (column with dop\$4 with sidewall with etchant adj gas)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:42
L4	0	voltage adj sustaining adj region and epitaxial and trench and column and (dop\$4 with sidewall with etchant adj gas)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:43
L5	8	voltage adj sustaining adj region and epitaxial and trench and column and (dop\$4 with etchant adj gas)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:43
L6	896	257/328.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:55
L7	750	257/329.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:55
L8	245	257/212.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:55

L9	955	257/341.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:55
L10	683	438/268.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:55
L11	859	438/200.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:55
L12	45	6 and voltage with sustain\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:56
L13	38	7 and voltage with sustain\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:56
L14	2	8 and voltage with sustain\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:56
L15	53	9 and voltage with sustain\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:56
L16	35	10 and voltage with sustain\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:56

L17	12	11 and voltage with sustain\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:57
L18	1	12 and ((dop\$4 or implant\$4) with etch\$4 with gas)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:57
L19	1	13 and ((dop\$4 or implant\$4) with etch\$4 with gas)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:57
L20	0	14 and ((dop\$4 or implant\$4) with etch\$4 with gas)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:58
L21	1	15 and ((dop\$4 or implant\$4) with etch\$4 with gas)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:58
L22	5	16 and ((dop\$4 or implant\$4) with etch\$4 with gas)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:58
L23	2	16 and ((dop\$4 or implant\$4) with etch\$4 with gas) same sidewall	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/17 06:58